

SINGLE-BEAM, PRIMARY-CURRENT-MODULATION TYPE REDISTRIBUTION WRITING CAPACITANCE-DISCHARGE READING

DATA
General:
Heater, for Unipotential Cathode: Voltage 6.3 ac or dc volts Current 0.6 amp Direct Interelectrode Capacitances (Approx.):
Grid No.1 to all other electrodes 6.5 $\mu\mu$ f Grid No.1 to deflecting electrode D ₁ 0.2 $\mu\mu$ f Grid No.1 to deflecting electrode D ₂ 0.2 $\mu\mu$ f Grid No.1 to deflecting electrode D ₃ 0.2 $\mu\mu$ f Grid No.1 to deflecting electrode D ₄ 0.2 $\mu\mu$ f Cathode to all other electrodes 5 $\mu\mu$ f D ₁ to D ₂ 2.8 $\mu\mu$ f D ₁₂ to D ₁₄
W_1 to all other electrodes
Deflecting-electrode arrangement
with the tube). Overall Length
Cap Recessed Small Cavity (JETEC No.J1-21) Base Small-Shell Duodecal 10-Pin (JETEC No.B10-75) BOTTOM VIEW
Pin 1-Heater Pin 2-Grid No.1 Pin 3-Cathode Pin 4-Grid No.3 Pin 6-Deflecting Electrode DJ Pin 7-Deflecting Electrode DJ Pin 7-Deflecting Electrode DJ Pin 8-Ultor (Grids No.2 & No.4)
The Signal-Output Electrode is capacitively coupled to the Storage Surface.





Maximum Ratings, Design-Center Values:	
COLLECTOR VOLTAGE:	
Difference between collector voltage and ultor voltage 150 max.	volts
ULTOR VOLTAGE	volts
GRID-No.3 VOLTAGE 1000 max.	volts
GRID-No.1 VOLTAGE:	vol+c
Negative bias value 200 max. Positive bias value 0 max.	volts volts
Positive peak value 2 max.	volts
PEAK VOLTAGE BETWEEN ULTOR AND	
ANY DEFLECTING ELECTRODE 500 max.	volts
PEAK HEATER-CATHODE VOLTAGE: Heater negative with	
respect to cathode 125 max.	volts
Heater positive with	
respect to cathode 125 max.	volts
Equipment Design Ranges:	
For any ultor voltage (E_{C_4}) between 1000 and 2500 vo	lts
Collector Voltage 95% to 105% of E _{C4}	volts
Grid-No.3 Voltage 20% to 28% of E _{C4}	volts
Max. Grid-No.1 Voltage for Beam-Current Cutoff 2.4% of E _C ₄	volts
Max. Grid-No.3 Current	10163
Range15 to +10	μamp
Deflection Factors:	of E
W1 & W2 39 to 53 v dc/in./kv W3 & W4 35.5 to 48.5 v dc/in./kv	of Eca
Focused-Beam Position. ##	
Examples of Use of Design Ranges:	
For ultor voltage of 1000 2500	volts
Collector Voltage 950 to 1050 2375 to 2625	volts
Grid-No.3 Voltage 200 to 280 500 to 700	volts
Max. Grid-No.1 Volt-	
age for Beam- Current Cutoff —24 —60	volts
Deflection Factors:	
D ₁ & D ₂ 39 to 53 97.5 to 133 volts	dc/in.
D3 & D4 35.5 to 48.5 89 to 122 volts	dc/in.
• The "ultor" in a storage tube is the electrode to which is appl	ied the
highest dc voltage for accelerating the electrons in the beam	
to its deflection. In the 6571, the ultor function is perfor	med by
to its deflection. In the 6571, the ultor function is perfor grid No.4. Since grid No.4 and grid No.2 are connected together the 6571, they are collectively referred to simply as "ultor" for	med by within
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Storage Characteristics for Ultor Voltage of 2500 Volts: Storage-Surface Boundary (In terms of deflection voltage): In the D1-D2 direction from position of undeflected focused beam . . volts ±109 In the DJ3-DJ4 direction from position of undeflected focused beam . . ±100 volts Blemish Factor*, for storage surface within indicated boundary. . . . 0.5 max. Spill (Determined for Double-Dot Pattern):** Under conditions involving 255 references to "spill" element and 1 reference to "test" element Separation Between Storage Elements, in either the D1-D2 or D3-D4 direction in terms of deflection voltage: At center of storage surface. volts 8 max. At midpoint on each side of 10 max. storage-surface boundary. volts Maximum Circuit Values: Grid-No.1-Circuit Resistance . 1.5 max. megohms Resistance in Any Deflecting-Electrode Circuit® 1.0 max. megohm Blemish factor is defined as the factor by which the normal positive signal is reduced by the blemish. Spill is indicative of the amount of binary information that can be stored by the tube. The storage capability is determined by the separation between two storage elements at which the signal from one element is changed by no more than a specified amount after repeated references to the other element. For the 6571, the separation is measured, in terms of deflection voltage, when the amplitude of the negative signal of the "test" element has decreased to 50% of its maximum negative amplitude. The maximum negative amplitude is determined by separating the two elements far enough to eliminate the effects of secondary electron redistribution from the "spill" element.

OPERATING CONSIDERATIONS

It is recommended that the deflecting-electrode-circuit resistances

Shielding. In typical computer applications, the 6571 is mounted in a compartment having effective magnetic and electrostatic shielding. It is recommended that the bulb be provided with a tight-fitting electrostatic shield extending from the base to the collector coating. Dimensional Outline). This external shield supplements the shielding action of the collector in preventing crosscoupling between the electron gun and the external signal electrode.

A signal-output electrode shaped to conform with the external contour of the faceplate and placed in contact with the entire area of the faceplate is required. signal-output electrode is connected to a low-noise video

be approximately equal.



amplifier having sufficient gain to amplify signals from a fraction of a millivolt to the desired level.

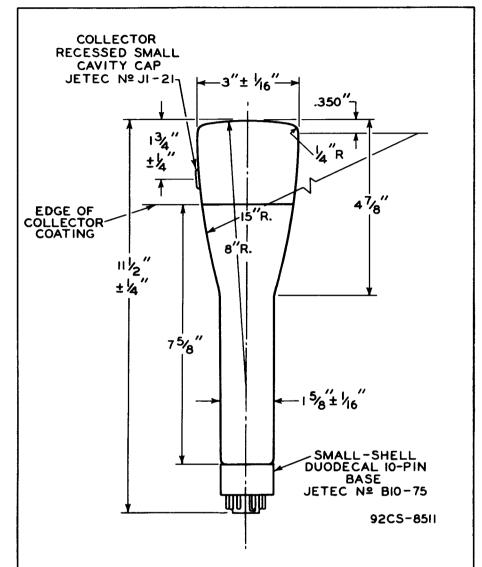
The amount of information that can be stored by the 6571 is dependent on the manner in which it is operated, and is affected by the stability of the deflecting system, freedom from noise in the associated output circuit, the number of regenerations compared with the number of addresses, and the effectiveness of the electrostatic and magnetic shielding.

In general, the number of storage elements is proportional to the operating ultor voltage. For the greatest number of storage elements, the 6571 should be operated at the rated maximum ultor voltage and so that the peak grid-No.1 drive is less than that required for the maximum positive amplitude but high enough to provide a satisfactory output signal.

It is recommended that the beam current be limited to the minimum value which provides satisfactory signal amplitude.

The storage characteristics in the tabulated data and curve are based on the use of a double-dot pattern. In this method of storage, the positive signal is produced by adjusting the beam current and the distance between two dot storage elements so that the optimum positive signal is produced when the "test" element is addressed. Other methods of storage such as superimposed focused and defocused spots or dots and dashes may be used equally well with the 6571.





CENTER LINE OF BULB WILL NOT DEVIATE MORE THAN 20 IN ANY DIRECTION FROM PERPENDICULAR ERECTED AT CENTER OF BOTTOM OF BASE.

DJ| AND DJ2 ARE NEARER THE STORAGE SURFACE: DJ3 AND DJ4 ARE NEARER THE BASE. WITH DJ POSITIVE WITH RESPECT TO DJ2, THE BEAM WILL BE DEFLECTED TOWARD PIN 2; LIKEWISE, WITH DJ3 POSITIVE WITH RESPECT TO DJ4, THE BEAM WILL BE DEFLECTED TOWARD VACANT PIN POSITION II.

THE PLANE THROUGH TUBE AXIS AND EACH OF THE FOLLOWING ITEMS MAY VARY FROM THE DEFLECTION PATH PRODUCED BY DJI AND DJ2 BY THE FOLLOWING ANGULAR TOLERANCES (MEASURED ABOUT THE TUBE AXIS): PIN 2, 100; SIDE TERMINAL (ON SAME SIDE AS PIN 8), 100. ANGLE BETWEEN DJ | -DJ2 DEFLECTION PATH AND DJ3-DJ4 DEFLECTION PATH IS 900 ± 30.





AVERAGE CHARACTERISTIC

